RL62M01A

Bluetooth® Low Energy Module

INTRODUCTION

RL62M01A is an ultra-low-power SoC module for Bluetooth® 5.0 low energy applications that combines the excellent performance of a leading RF transceiver with a low-power ARM® Cortex-M4F. RL62M01A supports transport mode that user can easily develop BLE related applications. The RL62M01A also supports piconet which can connect one smart phone and three peripheral devices or connect 4 peripheral devices at the same time.

FEATURES

- Bluetooth® Core Spec v5.0 compliant
- Supports 2Mbps LE, LE advertising extension and LE long range
- Supports GAP, ATT/GATT, SMP, L2CAP
- Supports OTA (Over-the-Air) for firmware upgrade
- **Battery Supply Voltage** 1.8V to 3.6V -20°C to +65°C **Operational Temperature**
- **Current Consumptions**

Power Down Mode 450nA (Typ.) Deep LPS (with 160K SRAM retention) Mode 2.5 - 2uA (Typ.)TX Mode (+0dBm) 8.5 mA (Typ.) TX Mode (+4dBm) 10.5 mA (Typ.) TX Mode (+8dBm) 12.8 mA (Typ.) **RX Mode** 6.7 mA (Typ.)

- Radio Bluetooth® Qualification (End Product, QDID: TBD)
- Meets Radio Certification FCC, RED, KCC and MIC Japan
- 11.05mm(W) x 17mm(L) x 2.05mm(H) Dimension
- Pb Free, RoHS Compliant

REVERSION HISTORY

Version Code	Date	Descriptions
0.1 BETA	23-JUL-20	Preliminary release

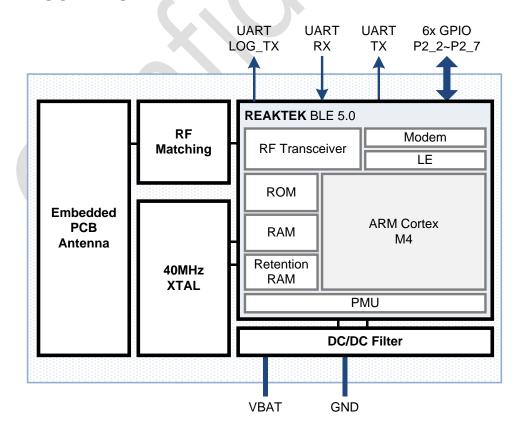




MODULE SPECIFICATIONS

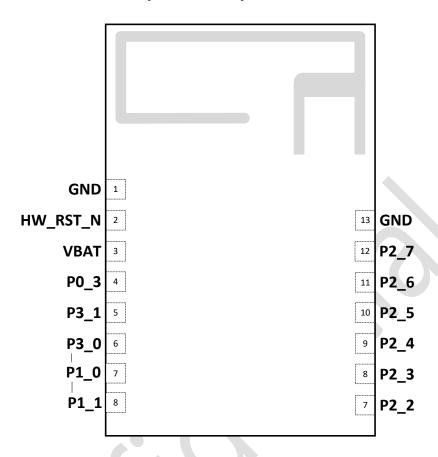
Specificat	ion Name	Descriptions
Module Dimension		11.05mm(W) x 17mm(L) x 2.05mm(H)
BLE Core Compliant		V5.0
Operation Distance		Up to 50 Meters (*LE 1M, apple to apple testing results)
Power Supply		1.8V – 3.6V
	Power Down Mode	450nA
	Deep LPS	2.5uA
D 6	TX mode (+0dBm)	8.4mA
Power Consumption	TX mode (+4dBm)	10.4mA
	TX mode (+8dBm)	12.7mA
	RX mode	6.8mA
Antenna Type	•	embedded PCB antenna
GPIO Numbers:		Up to 8x (including P3_0 and P3_1)
PWM Numbers:		Up to 6x (P2_2 to P2_7)
12bit ADC Numbers:		Up to 6x (P2_2 to P2_7)
Support interfaces		UART/4-wire SPI master or slave/I ² S master/PCM master

■ BLOCK DIAGRAM •



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PIN ASSIGNMENTS (TOP VIEW)



PIN DEFINITIONS

Note: INOUT (digital bidirectional), ANA(analog pin), DIG(digital pin).

#	Pin Name	I/O	Ana/Dig	Function
1	1 GND -		GND	GND
2	2 HW_RST_N IN		DIG	Hardware reset pin; low active;
3	3 VBAT - PV		PWR	Power Supply, 1.8V to 3.6V;
4	P0_3	OUT	DIG	LOG_UART_TX (default)
5	P3_1	INOUT	DIG	HCI_UART_RX (default) General purpose IO, 8mA driving capability; With wakeup function, internal strong/weak pull-up and pull-down;
6	P3_0	INOUT	DIG	HCI_UART_TX (default) General purpose IO, 8mA driving capability; With wakeup function, internal strong/weak pull-up and pull-down;

			I	
				AUXADC input 2 (default)
7	P2_2	2_2 INOUT		General purpose IO, 8mA driving capability;
				With wakeup function, internal strong/weak pull-up and pull-
				down;
				AUXADC input 3 (default)
8	na a	INOUT	ANA/DIG	General purpose IO, 8mA driving capability;
0	P2_3	INOUT	ANAJDIG	With wakeup function, internal strong/weak pull-up and pull-
				down;
				AUXADC input 4 (default)
	D2 4	MOUT	AAIA /DIG	General purpose IO, 8mA driving capability;
9	P2_4	INOUT	ANA/DIG	With wakeup function, internal strong/weak pull-up and pull-
				down;
				AUXADC input 5 (default)
10	D2 F	INOLIT	ANIA /DIC	General purpose IO, 8mA driving capability;
10	P2_5	INOUT	ANA/DIG	With wakeup function, internal strong/weak pull-up and pull-
				down;
				AUXADC input 6 (default)
	D2 6	MOUT	AAIA /DIG	General purpose IO, 8mA driving capability;
11	P2_6	INOUT	ANA/DIG	With wakeup function, internal strong/weak pull-up and pull-
				down;
				AUXADC input 7 (default)
12	D2 7	INCLIT	ANIA /DIC	General purpose IO, 8mA driving capability;
12	P2_7	INOUT	ANA/DIG	With wakeup function, internal strong/weak pull-up and pull-
				down;
13	GND		GND	GND



INTERFACE DESCRIPTIONS

UART

RL62M01A provides multiple UART baud-rate. The common baud-rate is shown in below table. The UART clock error between two devices should be less than +/-

RL62M01A UART Features:

- Supports 7/8 data format.
- ➤ 1/2 bit stop bit.
- Configurable parity bit: odd/even.
- Programmable baud rate (maximum baud rate=4Mbps).
- Support hardware flow control.
- RX line idle state detect.
- DMA supported.

Baud-rate (bps)	Error (%)	Baud-rate (bps)	Error (%)
1200	-0.23	460800	0.17
9600	< 0.01	500000	< 0.01
14400	< 0.01	921600	0.18
19200	< 0.01	1000000	< 0.01
28800	< 0.01	1382400	0.17
38400	< 0.01	1444400	-0.31
57600	< 0.01	1500000	< 0.01
76800	0.01	1843200	-0.35
115200	< 0.01	2000000	0.02
128000	0.02	2764800	0.14
153600	-0.1	3000000	0.06
230400	0.03	400000	0.03

Table: UART Baud Rate



ELECTRICAL CHARACTERISTICS

Temperature Limit Ratings

Parameter	Description	Note	Min.	Тур.	Max.	Unit
T _{STORE}	Storage temperature		-45		100	°C
T _{AOP}	Operational Temperature		-20		65	°C

Power Supply DC Characteristics

Parameter	Description	Note	Min.	Тур.	Max.	Unit
V _{BAT}	Supply Voltage		1.8	3	3.6	>

ESD Characteristics

Parameter	Description	Note	Min.	Тур.	Max.	Unit
ESD _{нвм}	ESD, human body mode	All pins, test method: JESD22			3500	V
ESD _{MM}	ESD, machine mode	All pins, test method: JESD22			200	V
ESD _{CDM}	ESD, charged device mode	All pins, test method: JESD22			500	V

12bit-AUX ADC Characteristics

Parameter	Description	Note	Min.	Тур.	Max.	Unit
ADC	Resolution	Bypass mode		12		BITS
ADCDNL ADCINL ADCVIN_RANGE	Resolution	Divided mode (1/3.3)		12		BITS
F _{CLK_ADC}	Clock Source	From digital			400	kHz
		Single-ended mode		±1.5		LSB
A D.C	DMI	(Bypass mode)		±1.5		LOD
ADCONL	DNL	Differential mode		±3.0		LSB
		(Bypass mode)		±3.0		LSB
	INL	Single-ended mode		±1.0		LSB
ADC		(Bypass mode)		11.0		LJB
ADCINE		Differential mode		±2.0		LSB
		(Bypass mode)				LJB
		External channel	0		VBAT	V
		(Divided Mode)	U		VDAI	V
۸DC	Input Voltage Range	External channel	0		1	
ADCVIN_RANGE	iliput voltage kalige	(Bypass Mode)	U		T	-
		Internal channel	1.8		3.63	V
		(VBAT)	1.0			V



ADC_{R_IN}	Input Impedance	Bypass mode	10M	Ohm
		Resistor divider mode (1/4)	500k	Ohm
ADC _{C_Sample}	Input Impedance	Bypass mode	1.9	pF
		Resistor divider mode (1/4)	1.9	pF

Radio Characteristics

General Radio Characteristics

Parameter	Description	Note	Min.	Тур.	Max.	Unit
F _{RANGE}	Frequency range		2402		2480	MHz

RX Performance

Condition: VBAT=3V, ambient temperature=25°C

Parameter	Description	Note	Min.	Тур.	Max.	Unit
P _{RX_MIN}	Sensitivity (LE 1M)	PER ≤ 30.8%	-97			dBm
P _{RX_MAX}	Maximum received power	PER ≤ 30.8%		-1		dBm
	C/I co-channel		21			dB
	C/I + 1MHz offset		15			dB
	C/I - 1MHz offset		15			dB
Clrx_1M	C/I + 2MHz offset		-17			dB
	C/I - 2MHz offset		-15			dB
	C/I + 3MHz offset		-27			dB
	C/I image		-9			dB
	C/I image + 1MHz offset		-15			dB
	C/I image - 1MHz offset		-15			dB
	C/I co-channel		21			dB
	C/I + 2MHz offset		15			dB
	C/I - 2MHz offset		15			dB
	C/I + 4MHz offset		-17			dB
CI _{RX_2M}	C/I - 4MHz offset		-15			dB
	C/I + 6MHz offset		-27			dB
	C/I image		-9			dB
	C/I image + 2MHz offset		-15			dB
	C/I image - 2MHz offset		-15			dB
	Blocker Power	30MHz ~ 2000MHz	-30			dBm
	Wanted signal level= -	2003MHz ~ 2399MHz	-30			dBm
Р _{RX_ООВ}	67dBm	2484MHz ~ 2997MHz	-30			dBm
	U/UDIII	3000MHz ~ 12.75GHz	-30			dBm

PER _{MAX}	Max PER report integrity	Wanted signal= -30dBm		50%	-
P _{RX_IMD}	Max Intermodulation level	Wanted signal f(0) = -64dBm	-50		
		Worst intermodulation level			dBm
		@2f1-f2=f0, f1-f2 =n MHz,			ивііі
		n=3,4,5			

TX Performance

Condition: VBAT=3V, ambient temperature=25°C

Parameter	Description	Note	Min.	Тур.	Max.	Unit
P _{TX_MAX}	Maximum output power				8	dBm
-	Adjacent channel power ratio	+2MHz			-20	dBm
		-2MHz			-20	dBm
		≥ +3MHz			-30	dBm
		≤ -3MHz			-30	dBm
P _{TX_ADJ}	Adjacent channel power ratio (LE 2M)	+4MHz			-20	dBm
		-4MHz			-20	dBm
		≥ +6MHz			-30	dBm
		≤ -6MHz			-30	dBm
		Δf1avg		250		kHz
	Modulation Characteristics	Δf2max	185			kHz
	(LE 1M)	Δf2max pass rate		100%		-
-		Δf2avg / Δf1avg		0.88		-
F _{MOD}		Δf1avg		500		kHz
	Modulation Characteristics	Δf2max	370			kHz
	(LE 2M)	Δf2max pass rate		100%		-
		Δf2avg / Δf1avg		0.88		-
	Coming for a company office to and	Average Fn		12.5		kHz
	Carrier frequency offset and drift	Drift rate		10		kHz/50μs
	(LE 1M)	Average drift		10		kHz/50μs
_	(LE IIVI)	Maximum drift		10		kHz/50μs
Fcar_offset	Carrier frequency offset and drift (LE 2M)	Average Fn		12.5		kHz
		Drift rate		10		kHz/50μs
		Average drift		10		kHz/50μs
	(LL ZIVI)	Maximum drift		10		kHz/50μs
P _{TX_HD2}	2 nd harmonic power			-50		dBm
P _{TX_HD3}	3 rd harmonic power			-50		dBm



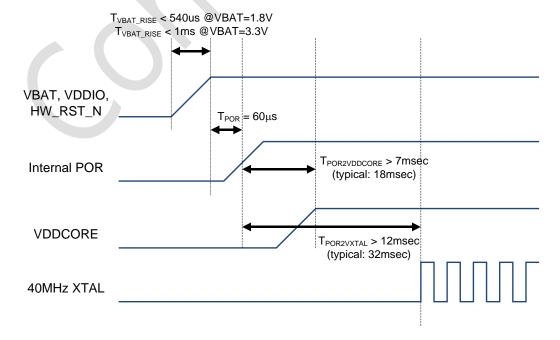
Digital I/O Pin DC Characteristics

Condition: ambient temperature=25°C

Parameter	Description	Note	Min.	Тур.	Max.	Unit
V _{IH33}	Input high voltage		2	3.3	3.6	V
V _{IL33}	Input low voltage	VDDIO=3.3V		0	0.9	V
V _{ОН33}	Output high voltage	VDDIO=3.3V	2.97		3.3	V
V _{OL33}	Output low voltage	VDDIO=2.8V e VDDIO=3.3V VDDIO=1.8V	0		0.33	V
V _{IH28}	Input high voltage		1.8	2.8	3.1	V
V _{IL28}	Input low voltage	VDDIO-3 8V		0	0.8	V
V _{OH28}	Output high voltage	VDDIO=2.8V	2.5			V
V _{OL28}	Output low voltage		0		0.28	V
	Strong Pull	VDDIO=3.3V		10		kOhm
		VDDIO=1.8V		20		kOhm
	M/I. D. II	VDDIO=3.3V		100		kOhm
D	Weak Pull	VDDIO=1.8V		200		kOhm
Kpull	R _{pull} Strong Pull VDD	VDDIO=3.3V		5		kOhm
	(P2_2~P2_7)	VDDIO=1.8V		2.5		kOhm
	Weak Pull	VDDIO=3.3V		50		kOhm
	(P2_2~P2_7)	VDDIO=1.8V		25		kOhm
Іін	Input high current	PAD configured as input			0.1	μΑ
IIL	Input low current	mode			0.1	μΑ

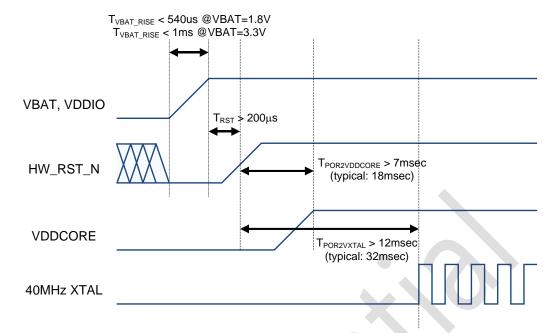
Boot Sequence

Boot up by internal power on reset circuit, power on timing is shown in below figure.

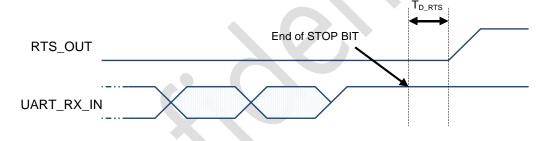


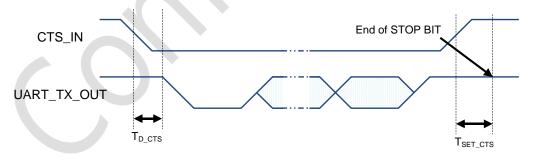


Boot up by HW_RST_N pin, power on timing is shown in below figure.



UART Characteristics

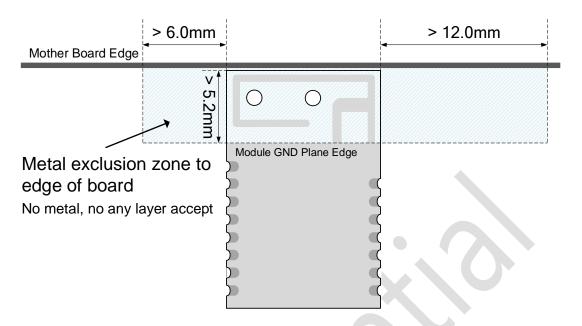


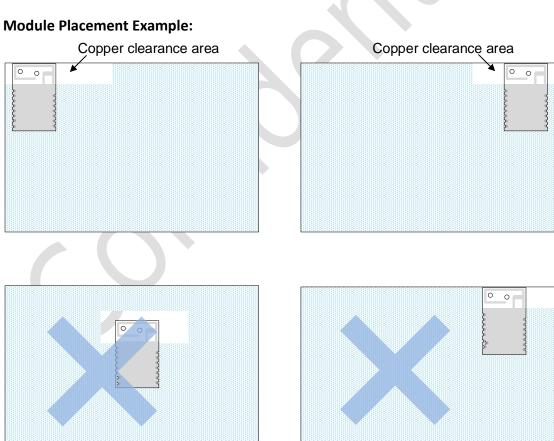


Parameter	Description	Note	Min.	Тур.	Max.	Unit
T_{D_RTS}	Timing between UART_RX_IN stop bit and RTS rising edge when RX FIFO is full				0.5	ns
T _{D_CTS}	Timing between CTS falling edge and UART_TX_OUT first bit				25	ns
T _{SET_CTS}	Timing between CTS rising edge and UART_TX_OUT stop bit		75			ns

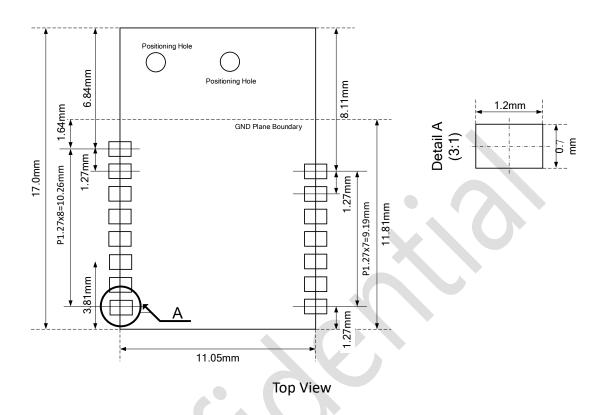


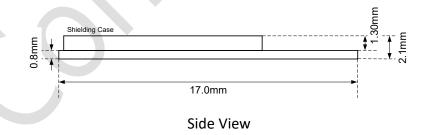
PCB LAYOUT GUIDE





MODULE DIMENTIONS





Federal Communication Commission Interference Statement

This equipment has been tested and found to comply with the limits for a Class B digital device, pursuant to Part 15 of the FCC Rules. These limits are designed to provide reasonable protection against harmful interference in a residential installation.

This equipment generates, uses and can radiate radio frequency energy and, if not installed and used in accordance with the instructions, may cause harmful interference to radio communications. However, there is no guarantee that interference will not occur in a particular installation. If this equipment does cause harmful interference to radio or television reception, which can be determined by turning the equipment off and on, the user is encouraged to try to correct the interference by one of the following measures:

- . Reorient or relocate the receiving antenna.
- . Increase the separation between the equipment and receiver.
- . Connect the equipment into an outlet on a circuit different from that to which the receiver is connected.
- . Consult the dealer or an experienced radio/TV technician for help.

FCC Caution: To assure continued compliance, any changes or modifications not expressly approved by the party responsible for compliance could void the user's authority to operate this equipment. (Example - use only shielded interface cables when connecting to computer or peripheral devices).

End Product Labeling

This transmitter module is authorized only for use in devices where the antenna may be installed such that 20 cm may be maintained between the antenna and users. The final end product must be labeled in visible area with the following: "Contains FCC ID: <u>2AXIJ-RL62M</u>"

End Product Manual Information

The user manual for end users must include the following information in a prominent location "IMPORTANT NOTE: To comply with FCC RF exposure compliance requirements, the antenna used for this transmitter must be installed to provide a separation distance of at least 20 cm from all persons and must not be colocated or operating in conjunction with any other antenna or transmitter." This device complies with part 15 of the FCC rules. Operation is subject to the following two conditions

- (1) This device may not cause harmful interference and
- (2) This device must accept any interference received, including interference that may cause undesired operation.

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IMPORTANT NOTE: In the event that these conditions can not be met (for example certain laptop configurations or colocation with another transmitter), then the FCC authorization is no longer considered valid and the FCC ID can not be used on the final product. In these circumstances, the OEM integrator will be responsible for reevaluating the end product (including the transmitter) and obtaining a separate FCC authorization. This device is intended only for OEM integrators under the following conditions: The antenna must be installed such that 20 cm is maintained between the antenna and users. As long as a condition above is met, further transmitter test will not be required. However, the OEM integrator is still responsible for testing their end product for any additional compliance requirements required with this module installed (for example, digital device emissions, PC peripheral requirements, etc.).